## NSN 5961-00-430-6346

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View Online at https://aerobasegroup.com/nsn/5961-00-430-6346 **Inclosure Material:** Metal **Overall Length:** 0.280 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0.60 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.435 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 33.0 collector to emitter voltage/static/base open and 65.0 collector to emitter voltage, dc with base short-circuited to emitter **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 23.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator: Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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